

VIBRONIC THEORY OF HETEROLIGAND SYSTEMS APPLIED TO STRUCTURAL PHASE TRANSITIONS IN SOME H-BONDED MATERIALS

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Received 30 August 1994, accepted 17 April 1995

Abstract. An approach to H-bonded molecular crystals, such as KDP, etc. is presented, which is based on the vibronic theory of ligand substitution effects. Any redistribution of protons over their potential energy minima is treated as a substitution $O_{O-H} \rightleftharpoons O_{O...H}$ in the molecular building units of a crystal. The pseudospin formalism is applied for the description of proton distributions. The Ising form of the total energy of the crystal is obtained. The Ising model parameters are expressed in terms of the MOs of the molecular building units of the crystal and can be estimated from quantum-chemical calculations. This approach allows one to give reasonable estimations of the Ising parameters and to explain the main chemical trends in ferroelectric properties for the KDP-family materials. Its application to the squaric acid is also discussed.

Key words: H-bonded crystals, order–disorder phase transitions.

The ferroelectric properties of H-bonded materials, such as KDP (KH_2PO_4), H_2SQ ($H_2C_4O_4$), etc. have been thoroughly studied [1, 2]. As to the theoretical models used for their microscopic description, they cannot be regarded as fully satisfactory, mainly due to the presence of some fitting parameters [2]. Therefore, it is purposeful to develop other approaches where the major parameters of the theory can be evaluated in terms of the composition and the electronic structure of the material under study. In this connection the vibronic theory of structural phase transitions [3, 4] and its application to H-bonded crystals [5–8] should be mentioned. In the latter, the origin of order–disorder phase transitions in KDP-like crystals is assumed to involve the pseudo-Jahn–Teller effect for their tetrahedral building units. Here a different approach to H-bonded materials is discussed, which is based on the vibronic theory of heteroligand systems [9] and the results of quantum-chemical calculations (see also [10]).

The effects of the ligand substitution $ML_n \rightarrow ML_{n-k}XY...Z$ are treated in this theory, and the perturbational treatment is applied for determination of the adiabatic potential for the heteroligand system $ML_{n-k}XY...Z$. The adiabatic potential of the homoligand system ML_n is regarded as a zero approximation and the perturbation operator has a form:

$$\mathfrak{H}C = \mathfrak{H}C_S + V, \quad V = \sum_v (\partial \mathfrak{H}C / \partial Q_v)_0 Q_v + \dots \quad (1)$$

Here V is the vibronic coupling operator for ML_n and $\mathfrak{H}C_S$ is the "substitution operator" describing the ligand replacement effect on the electronic subsystem of ML_n in its equilibrium molecular geometry.

The case of closed electronic shells of ML_n and $ML_{n-k}XY...Z$ is considered. Then for the lowest sheet of the adiabatic potential of $ML_{n-k}XY...Z$ we have

$$E_1(Q) = 1/2 \sum_v K_v Q_v^2 + S_0 - 2 \sum_{m \neq n} (S_{nm}^2 / \omega_{nm}) - 4 \sum_{m \neq n} \sum_v (S_{nm} A_{nm}^v / \omega_{nm}) Q_v. \quad (2)$$

In Eq. (2), $E_1(Q)$ is the total energy of $ML_{n-k}XY...Z$ as a function of the normal (symmetry) coordinates Q_v of ML_n , and K_v and A_{nm}^v are the force and orbital linear vibronic constants of ML_n , respectively. The ω_{nm} are the energy gaps between the occupied (ψ_n) and the unoccupied (ψ_m) MOs of ML_n , and S_{nm} denotes the matrix elements of the one-electron substitution operator H_S in this MOs basis set. Therefore one has

$$A_{nm}^v = \langle \psi_n | (\partial H / \partial Q_v)_0 | \psi_m \rangle, \quad S_{nm} = \langle \psi_n | H_S | \psi_m \rangle, \quad (3)$$

where H is the one-electron Hamiltonian of ML_n and ψ_n , ψ_m are its eigenfunctions. It is easy to obtain the difference between the total energies of $ML_{n-k}XY...Z$ and ML_n in their equilibrium configurations Q^f and $Q^0 = 0$, respectively. Using the conditions $\partial E_1(Q) / \partial Q_v = 0$, one has from Eq. (2)

$$E_1(Q^f) - E(0) = S_0 - 2 \sum_{m \neq n} S_{nm}^2 / \omega_{nm} - 4 \sum_v K_v^{-1} (\sum_{m \neq n} S_{nm} A_{nm}^v / \omega_{nm})^2. \quad (4)$$

The analysis of the H-bonded molecular crystals under study is based on Eq. (4). Let us consider, for instance, the KDP-family crystals (Fig. 1). The AO_4 tetrahedra ($A = P, As$) in their lattices are bounded via H-bonds. Each oxygen atom of any tetrahedron exists in one of the two states because the proton's potential curve has two equivalent minima: these states are O_{O-H} and $O_{O...H}$. Any proton redistribution over their equilibrium sites on H-bonds can be treated as an $O_{O-H} \rightleftharpoons O_{O...H}$ replacement in the apices of these AO_4 tetrahedra. This "substitution" has a cooperative character because the $O_{O-H} \rightleftharpoons O_{O...H}$ transformation in a

given apex of any tetrahedron results in reverse transformation in the neighbouring tetrahedron:

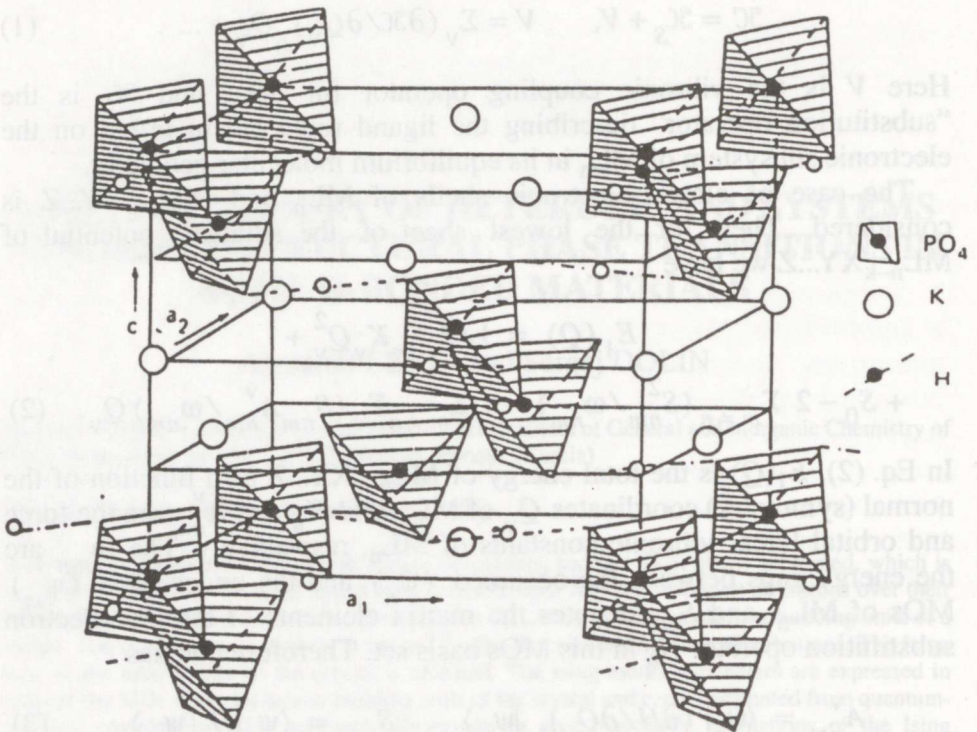
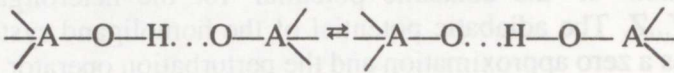


Fig. 1. The structure of a KDP crystal.

For the protons on the H-bonds of a crystal it is useful to apply pseudospin formalism. In this formalism two values $\sigma_j = \pm 1$ of the pseudospin σ_j correspond to two equilibrium proton positions on the j th H-bond. Then one can obtain the Ising form of the total energy expression of a crystal, i.e.

$$E = C - 1/2 \sum_{i \neq j} J_{ij} \sigma_i \sigma_j \quad (5)$$

By using Eq. (4) the Ising model parameters J_{ij} from Eq. (5) can be expressed in terms of the electronic structure of the material.

Let us consider the AO_4 tetrahedron MOs in the basis of the valence ns , $np(\text{A})$ AOs and σ AOs of oxygen atoms (Fig. 2). The MO scheme is shown for the hypothetical proton positions at the H-bond centres (this scheme takes into account the realistic S_4 symmetry of the $\text{AO}_4(\text{H})_4$ moiety in the crystal rather than the T_d one. The b-e splitting is assumed to be small as compared with the gap (2Δ) between the highest occupied b, e MOs (HOMO) and the lowest unoccupied a^* MO (LUMO).

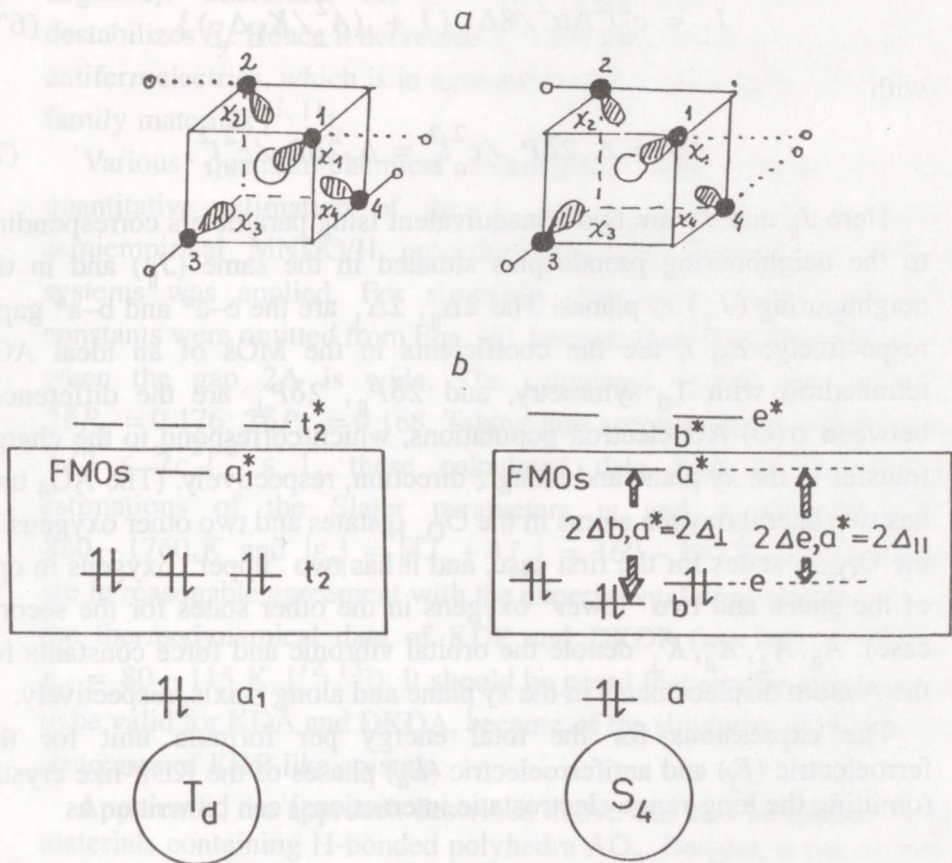


Fig. 2. The oxygen σ AOs participating in the A-O bonds (a) and σ MOs scheme for the AO_4 tetrahedron (b).

The proton transfers from the hypothetical positions to the actual ones change the orbital energies (α) of the σ (O) AOs participating in the A-O bonds. These changes are $\pm\Delta\alpha$ depending on the oxygen final state: O_{O-H} or $O_{O...H}$. In such way each distribution of pseudospins determines the σ (O) orbital energies of all AO_4 tetrahedra, i.e. the (diagonal) substitution operator matrix in the AOs basis set of these tetrahedra.

For simplicity the frontier MOs (b, e, a^*) approximation is used to evaluate $E_1(Q^f)$ for each AO_4 tetrahedron from Eq. (4). Thus the total energy of the crystal is the sum of these quantities over all crystal tetrahedra. Here the "cooperative" coupling of the $O_{O-H}/O_{O...H}$ states should be taken into account for the neighbouring tetrahedra. Then the sum of the S_0 terms vanishes, while the sum of the other terms has the Ising form (Eq. (5)), and the Ising parameters are

$$J_{\parallel} = c_a^2 l_t^2 \Delta \alpha^2 / 8 \Delta_{\perp} \times \{ 1 + (A_{\perp}^2 / K_{\perp} \Delta_{\perp}) - 2(\Delta_{\perp} / \Delta_{\parallel}) - 2(A_{\parallel}^2 \Delta_{\perp} / K_{\parallel} \Delta_{\parallel}^2) \}, \quad (6')$$

$$J_{\perp} = c_a^2 l_t^2 \Delta \alpha^2 / 8 \Delta_{\perp} \{1 + (A_{\perp}^2 / K_{\perp} \Delta_{\perp})\} \quad (6'')$$

with

$$\Delta \alpha = \Delta_{\perp} 2 \delta P_{\perp} / c_a^2 l_t^2 = \Delta_{\parallel} 2 \delta P_{\parallel} / c_a^2 l_t^2. \quad (7)$$

Here J_{\parallel} and J_{\perp} are two nonequivalent Ising parameters corresponding to the neighbouring pseudospins situated in the same (J_{\parallel}) and in the neighbouring (J_{\perp}) xy planes. The $2\Delta_{\parallel}$, $2\Delta_{\perp}$ are the e-a* and b-a* gaps, respectively; c_a , l_t are the coefficients in the MOs of an ideal AO_4 tetrahedron with T_d symmetry, and $2\delta P_{\parallel}$, $2\delta P_{\perp}$ are the differences between $\sigma(O)$ AO electron populations, which correspond to the charge transfer in the xy plane and along z direction, respectively. (The AO_4 unit has two lateral oxygen atoms in the $O_{O\dots H}$ states and two other oxygens in the O_{O-H} states for the first case, and it has two "upper" oxygens in one of the states and two "lower" oxygens in the other states for the second case). A_{\parallel} , A_{\perp} , K_{\parallel} , K_{\perp} denote the orbital vibronic and force constants for the A atom displacements in the xy plane and along z -axis, respectively.

The expressions for the total energy per formula unit for the ferroelectric (E_f) and antiferroelectric (E_a) phases of the KDP-like crystal (omitting the long-range electrostatic interactions) can be written as

$$E_f = -2J_{\perp} - \epsilon_0/2, \quad E_a = -2J_{\perp} + \epsilon_0/2. \quad (8)$$

Here $\epsilon_0 = 4J_{\parallel} + 4J_{\perp}$, ($|\epsilon_0|$ is about 0,1 J_{\perp} in accordance with quantum-chemical calculations; see below).

Equations (6-8) permit us to give a qualitative explanation for some of the main trends in the behaviour of KDP-like materials. It is well known that the $R_{O-D} < R_{O-H}$ and $R_{O\dots D} > R_{O\dots H}$ inequalities are valid for the H- and D-bonds. Hence we have $\delta P(D) > \delta P(H)$ and $J_{\perp}(D) > J_{\perp}(H)$. Thus, $|E_f|$ and $|E_a|$ increase for a deuterated material, which is in agreement with experimental data that show the increasing of T_c for both deuterated ferroelectrics and antiferroelectrics [1, 11]. We are also able to explain the effect of the P \rightarrow As replacement. The energy gaps in molecules and crystals usually become narrower when the atomic numbers of the constituent atoms increase. The quantum-chemical calculations of different AO_4 -containing clusters ($A = P, As$), in particular, $H_4AO_4^+$, reproduce this trend. The decreasing of the HOMO-LUMO gap leads to the increasing of the quantities $\Delta_{\perp}/\Delta_{\parallel}$, $A_{\perp}^2/K_{\perp}\Delta_{\perp}$, and $(\Delta_{\parallel}^2/K_{\parallel}\Delta_{\parallel}) : (A_{\perp}^2/K_{\perp}\Delta_{\perp})$. As a result, the value of $|\epsilon_0|$ increases (ϵ_0 is

negative). Therefore, the $P \rightarrow As$ replacement stabilizes E_a and destabilizes E_f . Hence it decreases T_c for ferroelectrics and increases T_c for antiferroelectrics, which is in agreement with experimental data for KDP-family materials [1, 11].

Various quantum-chemical calculations were carried out for a quantitative estimation of the J_{\parallel} and J_{\perp} values. In particular, a semiempirical MNDO/H procedure specially adapted for H-bonded systems was applied. For simplicity, the terms containing vibronic constants were omitted from Eqs. (6), because their contributions are small when the gap 2Δ is wide. The calculated values are $2\Delta = 12$ eV, $2\delta P_{\parallel} = 0.176$, $2\delta P_{\perp} = 0.168$. Taking into account the obvious inequality $1/2 \leq 2c_a^2 l_t^2 \leq 1$, these calculated data lead to the following estimations of the Slater parameters w and ϵ_0 : $w = 2J_{\parallel} + 4J_{\perp} = 880 - 1760$ K and $|\epsilon_0| = |4J_{\parallel} + 4J_{\perp}| = 160 - 320$ K. These estimates are in reasonable agreement with the experimental ones obtained by using the thermodynamical data of KDP and DKDP ($w = 800 - 1100$ K and $\epsilon_0 = 80 - 115$ K, [12, 13]). It should be noted that similar estimates seem to be valid for KDA and DKDA, because of the similarity of the electronic structures of KDP-like crystals.

Apparently, the approach described above can also be applied to other materials containing H-bonded polyhedra AO_n . Besides, it can as well be applied to some different systems such as squaric acid (H_2SQ). The latter is a layered molecular crystal (Fig. 3), which is usually referred to as a two-dimensional analogue of KDP. We shall consider the "C₄-core" of the H_2SQ molecule as a pseudoatom surrounded by four O(H) ligands. The valence orbitals of this pseudoatom are the σ and π MOs of the C₄-core containing $\sigma(C)$ and $\pi(C)$ AOs which participate in the C–O bonds. It is easy to obtain the expression for the total energy of the H_2SQ layer in a form of Eq. (5). As earlier, we omit the vibronic contributions for simplicity. Then, for the independent Ising parameters we have

$$\begin{aligned}
 J_{cis} &= -c_a^2 l_b^2 \Delta \alpha_{\sigma}^2 / 8\Delta_{b_g a_g^*} - c_a^2 c_b^2 \Delta \alpha_{\pi}^2 / 8\Delta_{a_u^* b_u^{**}}, \\
 J_{tr} &= J_{cis} + c_a^2 l_e^2 \Delta \alpha_{\sigma}^2 / 4\Delta_{e_u a_g^*} + c_e^2 l_b^2 \Delta \alpha_{\sigma}^2 / 4\Delta_{b_g e_u^*} + \\
 &\quad + c_a^2 c_e^2 \Delta \alpha_{\pi}^2 / 4\Delta_{a_u^* e_g^{**}}. \tag{9}
 \end{aligned}$$

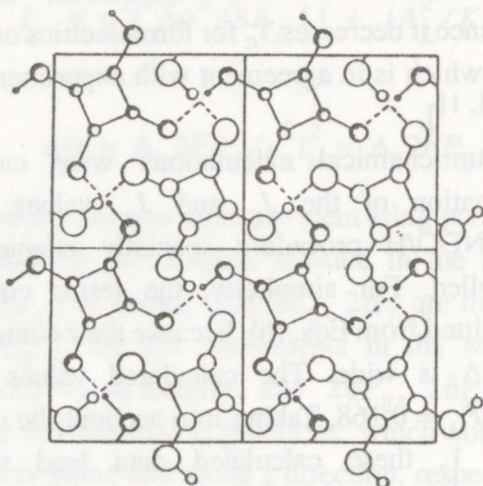


Fig. 3. The layer structure in the H_2SQ crystal (low-temperature phase).

Here J_{cis} and J_{tr} refer to a pseudospin coupling in the *cis* and *trans* positions of the C_4O_4 -fragment, respectively; c_{a_g} , l_{b_g} , etc. are the coefficients in the MOs of the C_4O_4 -fragment, and $2\Delta_{b_g a_g^*}$, etc. are the gaps between these MOs. $\Delta\alpha_\sigma$ and $\Delta\alpha_\pi$ are the variations of the $\sigma(O)$ and $\pi(O)$ AOs energies depending upon the state of the oxygen atom (O_{O-H} or $O_{O...H}$). One can express $\Delta\alpha$ in terms of the electronic populations of the $\sigma(O)$ and $\pi(O)$ AOs (on the analogy of Eq. (7)).

In conclusion, let us point out the physical meaning of Eqs. (6) and (9). These were obtained from Eq. (4) and they correspond to the change of the internal energy of the H-bonded molecular units of a crystal due to proton rearrangement on their H-bonds. Thus, a mechanism of the indirect pseudospin interaction in the crystal can be proposed, which is connected with the electronic and the geometrical reorganization of the non-hydrogen framework of a crystal. The numerical estimations for the Ising parameters of KDP-like crystals mentioned above evidence that such molecular mechanism is important and may be predominant.

ACKNOWLEDGEMENT

This work was supported by the Russian Fundamental Sciences Foundation, grant No. 93-03-18530.

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HETEROLIGANDILISTE SÜSTEEMIDE VIBROONTEOORIA RAKENDAMINE STRUKTUURSETELE FAASISIIRETELE MÕNEDES VESINIKSIDEMEGA MATERJALIDES

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On esitatud KDP-tüüpi vesiniksidemega molekulaarkristallide käsitus, mis põhineb ligandide asendusefektide vibroonteoorial. Prootonite ümberjaotumist potentsiaalenergia miinimumide vahel on vaadeldud asendusena $O_O-H^{\pm}O_O...H$ kristalli molekulaarsetes struktuuriüksustes. Prootonite jaotuse kirjeldamiseks on rakendatud pseudospinni formalismi. Kristalli koguenergia on antud Isingi kujus, kus Isingi parameetrid avalduvad kristalli struktuuriüksuste molekuliorbitaalide termineis ja on hinnatavad kvantmehaaniliste arvutuste abil. See käsitus võimaldab anda Isingi parameetritele mõistlikud hinnangväärtused ja selgitada KDP-tüüpi materjalide senjettelektriliste omaduste põhilisi "keemilisi" tendentse.

ВИБРОННАЯ ТЕОРИЯ ГЕТЕРОЛИГАНДНЫХ СИСТЕМ В ПРИМЕНЕНИИ К СТРУКТУРНЫМ ФАЗОВЫМ ПЕРЕХОДАМ В НЕКОТОРЫХ Н-СВЯЗАННЫХ МАТЕРИАЛАХ

Александр ЛЕВИН, Сергей ДОЛИН

Предложен подход к Н-связанным молекулярным кристаллам типа KDP и т. п. на основе вибронной теории эффектов замещения

лигандов. Любое перераспределение протонов по минимумам их потенциальной энергии рассматривается как замещение $O_O-H^{\pm}O_O...H$ в молекулярных структурных единицах кристалла. Для описания распределения протонов применен псевдоспиновый формализм. Полная энергия кристалла получена в форме Изинга, где параметры Изинга выражаются в терминах МО молекулярных структурных единиц кристалла и могут быть оценены из квантовохимических расчетов. Этот подход позволил получить разумные оценки параметров Изинга и объяснить основные "химические" тенденции в сегнетоэлектрических свойствах материалов семейства KDP. Обсуждено также применение предложенного подхода к квадратной кислоте.